preliminary

$V_{RRM} = 100V$

$$I_{FAV} = 2x \quad 15A$$

$$V_F = 0.72V$$

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

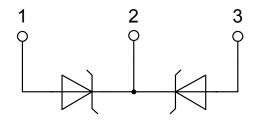
Schottky Diode Gen²

Part number

DSA30C100QB



Backside: cathode



Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-3P

- Industry standard outline compatible with TO-247
- RoHS compliant
- Epoxy meets UL 94V-0





preliminary

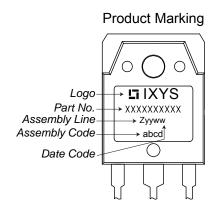
Schottky					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V _{RSM}	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			100	V
V _{RRM}	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			100	V
I _R	reverse current, drain current	V _R = 100 V	$T_{VJ} = 25^{\circ}C$			250	μΑ
		$V_R = 100 V$	$T_{VJ} = 125^{\circ}C$			2.5	mΑ
V _F	forward voltage drop	I _F = 15 A	$T_{VJ} = 25^{\circ}C$			0.91	V
		$I_F = 30 \text{ A}$				1.06	V
		I _F = 15 A	T _{VJ} = 125°C			0.72	V
		$I_F = 30 \text{ A}$				0.90	V
I _{FAV}	average forward current	T _c = 150°C	T _{vJ} = 175°C			15	Α
		rectangular d = 0.5					i
V _{F0}	threshold voltage		T _{vJ} = 175°C			0.46	V
r _F	slope resistance \(\) for power lo	oss calculation only				11.7	mΩ
R _{thJC}	thermal resistance junction to cas	e				1.75	K/W
R _{thCH}	thermal resistance case to heatsing	nk			0.25		K/W
P _{tot}	total power dissipation		$T_C = 25^{\circ}C$			85	W
I _{FSM}	max. forward surge current	$t = 10 \text{ ms}$; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			340	Α
C	junction capacitance	V _R = 12 V f = 1 MHz	T _{VJ} = 25°C		146		pF



DSA30C100QB

preliminary

Package TO-3P				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I _{RMS}	RMS current	per terminal 1)			50	Α	
T _{VJ}	virtual junction temperature		-55		175	°C	
T _{op}	operation temperature		-55		150	°C	
T _{stg}	storage temperature		-55		150	°C	
Weight				5		g	
M _D	mounting torque		0.8		1.2	Nm	
F _c	mounting force with clip		20		120	Ν	



Part number

D = Diode

S = Schottky Diode

A = low VF

30 = Current Rating [A] C = Common Cathode

100 = Reverse Voltage [V] QB = TO-3P (3)

Ordering	Part Number	Marking on Product	Delivery Mode Quantity		Code No.	
Standard	DSA30C100QB	DSA30C100QB	Tube	30	503339	

Similar Part	Package	Voltage class
DSA30C100HB	TO-247AD (3)	100
DSA30C100PB	TO-220AB (3)	100
DSA30C100PN	TO-220ABFP (3)	100

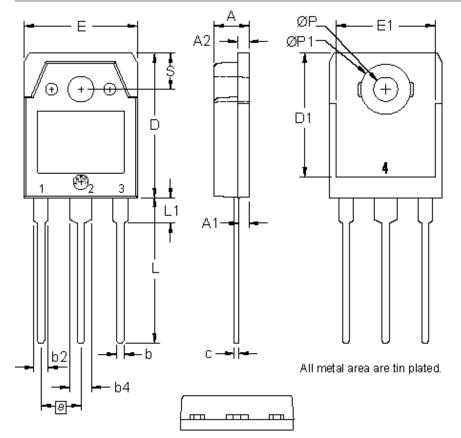
Equiva	alent Circuits for	Simulation	* on die level	T _{VJ} = 175 °C
$I \rightarrow V_0$	R _o -	Schottky		
V _{0 max}	threshold voltage	0.46		V
R _{0 max}	slope resistance *	9.1		$m\Omega$





preliminary

Outlines TO-3P



Dim.	Millimeter		Inches		
Dim.	min	max	min	max	
Α	4.70	4.90	0.185	0.193	
A1	1.30	1.50	0.051	0.059	
A2	1.45	1.65	0.057	0.065	
b	0.90	1.15	0.035	0.045	
b2	1.90	2.20	0.075	0.087	
b4	2.90	3.20	0.114	0.126	
С	0.55	0.80	0.022	0.031	
D	19.80	20.10	0.780	0.791	
D1	16.90	17.20	0.665	0.677	
Е	15.50	15.80	0.610	0.622	
E1	13.50	13.70	0.531	0.539	
е	5.45	BSC	0.215 BSC		
L	19.80	20.20	0.780	0.795	
L1	3.40	3.60	0.134	0.142	
ØР	3.20	3.40	0.126	0.134	
ØP1	6.90	7.10	0.272	0.280	
S	4.90	5.10	0.193	0.201	

